FREE

**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 3.0 A



www.vishay.com

Anode -0

SMC (DO-214AB)

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	3.0 A			
V <sub>R</sub>	60 V			
V <sub>F</sub> at I <sub>F</sub>	0.52 V			
I <sub>RM</sub>	20 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	5.0 mJ			
Package	SMC (DO-214AB)			
Circuit configuration	Single			

### **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS term reliability COMPLIANT HALOGEN
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-30BQ060-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

### **MECHANICAL DATA**

Case: SMC (DO-214AB) Molding compound meets UL 94 V-0 flammability rating Terminals: matte tin plated leads, solderable per J-STD-002 Polarity: color band denotes cathode end

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	3.0	Α		
V <sub>RRM</sub>		60	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1200	А		
V <sub>F</sub>	3.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.52	V		
TJ	Range	-55 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-30BQ060-M3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	60	N/	
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average ferward aurrent		50 % duty cycle at $T_L = 123 \text{ °C}$	, rectangular waveform	3.0	
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_L = 113 \text{ °C}$	, rectangular waveform	4.0	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	1200	А
non-repetitive surge current at T <sub>C</sub> = 25 °C	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	130	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.0 A, L = 10 mH		5.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1.0		А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		3 A	т ог %О	0.58	V
Maximum forward voltage drop	V <sub>EM</sub> <sup>(1)</sup>	6 A	- T <sub>J</sub> = 25 °C	0.76	
Maximum forward voltage drop	VFM <sup>(1)</sup>	3 A	- T <sub>J</sub> = 125 °C	0.52	
		6 A		0.66	
Maximum reverse leakage current			V Deted V	0.5	mA
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	20	IIIA
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to1 MHz), 25 °C		180	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		3.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000		V/µs	

#### Note

 $^{(1)}$  Pulse width = 300  $\mu s,$  duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	T <sub>J</sub> <sup>(1)</sup>		EE to 1150	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-55 to +150		
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>		12		
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	46	°C/W	
Approvimeto weight			0.24	g	
Approximate weight			0.008	oz.	
Marking device		Case style SMC (DO-214AB)	ЗН		

### Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink (1)

(2) Mounted 1" square PCB



# VS-30BQ060-M3

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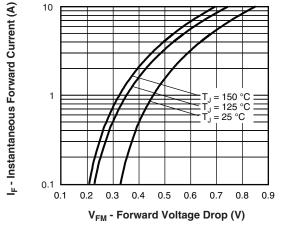


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

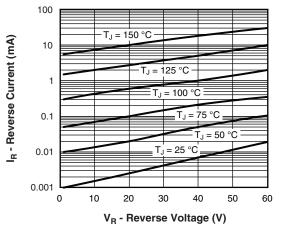


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

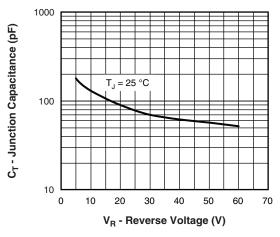


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

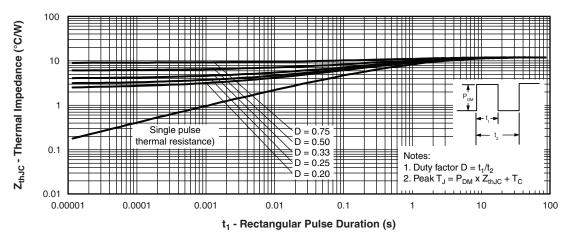


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics (Per Leg)

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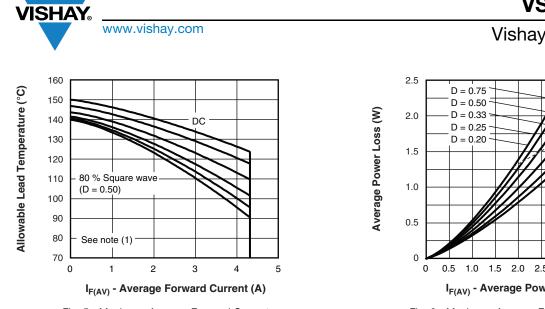


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

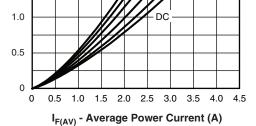


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

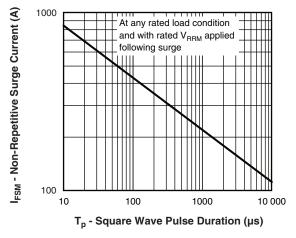


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R at V_{R1} = 80 \%$  rated  $V_R$ 

VS-30BQ060-M3

RMS limit

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### **ORDERING INFORMATION TABLE**

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Device code	VS-	30	В	Q	060	-M3	
	1	2	3	4	5	6	I
	1 - 2 - 3 -	Cur	hay Serr rrent ratii SMC		ctors pro	oduct	
	4 -	Q =	Schottk	ky "Q" se	eries		
	5 -	Vol	tage rati	ng (060	= 60 V)	)	
	6 -	Env	vironmer	ntal digit	:		
		-M3	= haloo	en_free	RoHS.	comolia	ant

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-30BQ060-M3/9AT	9AT	3500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95402		
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		
SPICE model	www.vishay.com/doc?96996		

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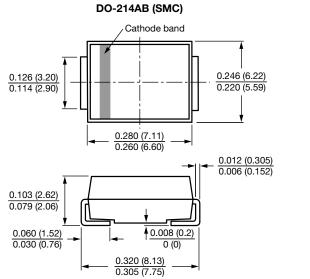


# **Outline Dimensions**

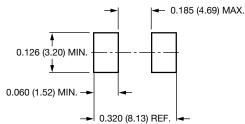
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SMC

### **DIMENSIONS** in inches (millimeters)



Mounting Pad Layout





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